

# **Octal Buffer/Line Driver** with 3-State Outputs

# 74AC240, 74ACT240

# **General Description**

The AC240/ACT240 is an octal buffer and line driver designed to be employed as memory and address driver, clock drivers and bus oriented transmitter or receiver which provides improved PC board density.

#### **Features**

- I<sub>CC</sub> and I<sub>OZ</sub> Reduced by 50%
- Inverting 3-State Outputs drive Bus Lines or Buffer Memory Address Registers
- Outputs Source/Sink 24 mA
- ACT240 has TTL-compatible Inputs
- These are Pb-Free Devices

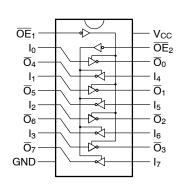


Figure 1. Connection Diagram

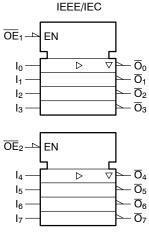
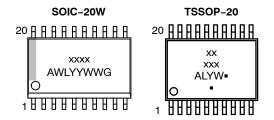


Figure 2. Logic Symbol

# SOIC-20W CASE 751D CASE 948E SOIC-20W CASE 751D CASE 948E TSOP-20 CASE 948AQ

#### **MARKING DIAGRAMS**



xxxx = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G or = Pb-Free Package
(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

#### **TRUTH TABLES**

Inputs		Outputs
ŌE <sub>1</sub>	In	(Pins 12, 14, 16, 18)
L	L	Н
L	Н	L
Н	X	Z

Inputs		Outputs
$\overline{\text{OE}}_2$	In	(Pins 3, 5, 7, 9)
L	L	Н
L	Н	L
Н	Х	Z

NOTE: H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

### **PIN DESCRIPTION**

Pin Names	Description
$\overline{OE}_1$ , $\overline{OE}_2$	3-State Output Enable Inputs
I <sub>0</sub> -I <sub>7</sub>	Inputs
$\overline{O}_0 - \overline{O}_7$	Outputs

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Rating	Unit
V <sub>CC</sub>	Supply Voltage	−0.5 to +7.0	V
I <sub>IK</sub>	DC Input Diode Current $V_{I} = -0.5 \text{ V}$ $V_{I} = V_{CC} + 0.5 \text{ V}$	-20 +20	mA
VI	DC Input Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
Іок	DC Output Diode Current $V_{O} = -0.5 \text{ V}$ $V_{O} = V_{CC} + 0.5 \text{ V}$	-20 +20	mA
Vo	DC Output Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
Io	DC Output Source or Sink Current	±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current per Output Pin	±50	mA
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
TJ	Junction Temperature	140	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage AC ACT	2.0 4.5	6.0 5.5	V
VI	Input Voltage	0	V <sub>CC</sub>	V
Vo	Output Voltage	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature	-40	85	°C
ΔV/Δt	Minimum Input Edge Rate, AC Devices: V <sub>IN</sub> from 30% to 70% V <sub>CC,</sub> V <sub>CC</sub> @ 3.3 V, 4.5 V, 5.5 V	125		mV/ns
ΔV/Δt	Minimum Input Edge Rate, ACT Devices: V <sub>IN</sub> from 0.8 V to 2.0 V, V <sub>CC</sub> @ 4.5 V, 5.5 V	125		mV/ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# DC ELECTRICAL CHARACTERISTICS FOR AC

				T <sub>A</sub> = +	-25°C	T <sub>A</sub> = -40°C to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Тур.	G	uaranteed Limits	Units
$V_{IH}$	Minimum HIGH Level	3.0	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V	1.5	2.1	2.1	V
	Input Voltage	4.5		2.25	3.15	3.15	
		5.5		2.75	3.85	3.85	
$V_{IL}$	Maximum LOW Level	3.0	$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$	1.5	0.9	0.9	V
	Input Voltage	4.5	]	2.25	1.35	1.35	
		5.5		2.75	1.65	1.65	
V <sub>OH</sub>	Minimum HIGH Level	3.0	I <sub>OUT</sub> = -50 μA	2.99	2.9	2.9	V
	Output Voltage	4.5	1	4.49	4.4	4.4	1
		5.5		5.49	5.4	5.4	
		3.0	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OH} = -12$ mA		2.56	2.46	
		4.5	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OH} = -24$ mA		3.86	3.76	
		5.5	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OH} = -24$ mA <sup>(1)</sup>		4.86	4.76	1
V <sub>OL</sub>	V <sub>OL</sub> Maximum LOW Level	3.0	I <sub>OUT</sub> = 50 μA	0.002	0.1	0.1	V
	Output Voltage	4.5		0.001	0.1	0.1	
		5.5	1	0.001	0.1	0.1	1
		3.0	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OL} = 12$ mA		0.36	0.44	
		4.5	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OL} = 24$ mA		0.36	0.44	1
		5.5	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OL} = 24$ mA <sup>(1)</sup>		0.36	0.44	1
I <sub>IN</sub> (Note 2)	Maximum Input Leakage Current	5.5	$V_I = V_{CC}$ , GND		±0.1	±1.0	μΑ
l <sub>OZ</sub>	Maximum 3-STATE Leakage Current	5.5	$\begin{aligned} &V_{l}\left(OE\right)=V_{lL}, &V_{lH}; &V_{l}=V_{CC}, &GND \\ &V_{O}=V_{CC}, &GND \end{aligned}$		±0.25	±2.5	μΑ
I <sub>OLD</sub>	Minimum Dynamic	5.5	V <sub>OLD</sub> = 1.65 V Max.			75	mA
I <sub>OHD</sub>	Output Current (Note 3)	5.5	V <sub>OHD</sub> = 3.85 V Min.			<b>-75</b>	mA
I <sub>CC</sub> (Note 2)	Maximum Quiescent Supply Current	5.5	V <sub>IN</sub> = V <sub>CC</sub> or GND		4.0	40.0	μΑ

<sup>1.</sup> All outputs loaded; thresholds on input associated with output under test.

<sup>2.</sup>  $I_{\text{IN}}$  and  $I_{\text{CC}}$  @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>. 3. Maximum test duration 2.0 ms, one output loaded at a time.

# DC ELECTRICAL CHARACTERISTICS FOR ACT

				T <sub>A</sub> = -	+25°C	T <sub>A</sub> = -40°C to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Тур.	G	iuaranteed Limits	Units
$V_{IH}$	Minimum HIGH Level	4.5	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V	1.5	2.0	2.0	٧
	Input Voltage	5.5		1.5	2.0	2.0	
$V_{IL}$	Maximum LOW Level	4.5	$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$	1.5	0.8	0.8	٧
	Input Voltage	5.5		1.5	0.8	0.8	
V <sub>OH</sub>	Minimum HIGH Level	4.5	I <sub>OUT</sub> = -50 μA	4.49	4.4	4.4	٧
	Output Voltage	5.5		5.49	5.4	5.4	
		4.5	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OH} = -24$ mA		3.86	3.76	
		5.5	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OH} = -24$ mA <sup>(4)</sup>		4.86	4.76	
V <sub>OL</sub>	V <sub>OL</sub> Maximum LOW Level		I <sub>OUT</sub> = 50 μA	0.001	0.1	0.1	٧
	Output Voltage	Output Voltage 5.5		0.001	0.1	0.1	1
		4.5	$V_{IN} = V_{IL}$ or $V_{IH}$ , $I_{OL} = 24$ mA		0.36	0.44	
		5.5	$V_{IN} = V_{IL} \text{ or } V_{IH}, I_{OL} = 24 \text{ mA}^{(4)}$		0.36	0.44	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	$V_I = V_{CC}$ , GND		±0.1	±1.0	μΑ
l <sub>OZ</sub>	Maximum 3-STATE Leakage Current	5.5	$V_I = V_{IL}, V_{IH}; V_O = V_{CC}, GND$		±0.25	±2.5	μΑ
I <sub>CCT</sub>	Maximum I <sub>CC</sub> /Input	5.5	$V_{I} = V_{CC} - 2.1 \text{ V}$	0.6		1.5	mA
I <sub>OLD</sub>	Minimum Dynamic	5.5	V <sub>OLD</sub> = 1.65 V Max.			75	mA
I <sub>OHD</sub>	Output Current (Note 5)	5.5	V <sub>OHD</sub> = 3.85 V Min.			<b>–75</b>	mA
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	V <sub>IN</sub> = V <sub>CC</sub> or GND		4.0	40.0	μΑ

<sup>4.</sup> All outputs loaded; thresholds on input associated with output under test.5. Maximum test duration 2.0 ms, one output loaded at a time.

# AC ELECTRICAL CHARACTERISTICS FOR AC

			T <sub>A</sub> = +2	25°C, C <sub>L</sub> =	50 pF	T <sub>A</sub> = -40°C to +8	35°C, C <sub>L</sub> = 50 pF	
Symbol	Parameter	V <sub>CC</sub> (V) (Note 6)	Min.	Тур.	Max.	Min.	Max.	Units
t <sub>PLH</sub>	Propagation Delay, Data to	3.3	1.5	6.0	8.0	1.0	9.0	ns
	Output	5.0	1.5	4.5	6.5	1.0	7.0	
t <sub>PHL</sub>	Propagation Delay, Data to	3.3	1.5	5.5	8.0	1.0	8.5	ns
	Output	5.0	1.5	4.5	6.0	1.0	6.5	
t <sub>PZH</sub>	Output Enable Time	3.3	1.5	6.0	10.5	1.0	11.0	ns
		5.0	1.5	5.0	7.0	1.0	8.0	
t <sub>PZL</sub>	Output Enable Time	3.3	1.5	7.0	10.0	1.0	11.0	ns
		5.0	1.5	5.5	8.0	1.0	8.5	
t <sub>PHZ</sub>	Output Disable Time	3.3	1.5	7.0	10.0	1.0	10.5	ns
		5.0	1.5	6.5	9.0	1.0	9.5	
t <sub>PLZ</sub>	Output Disable Time	3.3	1.5	7.5	10.5	1.0	11.5	ns
		5.0	1.5	6.5	9.0	1.0	9.5	

<sup>6.</sup> Voltage range 3.3 is 3.3 V  $\pm$  0.3 V. Voltage range 5.0 is 5.0 V  $\pm$  0.5 V.

# AC ELECTRICAL CHARACTERISTICS FOR ACT

			T <sub>A</sub> = +2	T <sub>A</sub> = +25°C, C <sub>L</sub> = 50 pF		$T_A = -40^{\circ}C$ to +85°C, $C_L = 50$ pF		
Symbol	Parameter	V <sub>CC</sub> (V) (Note 7)	Min.	Тур.	Max.	Min.	Max.	Units
t <sub>PLH</sub>	Propagation Delay, Data to Output	5.0	1.5	6.0	8.5	1.5	9.5	ns
t <sub>PHL</sub>	Propagation Delay, Data to Output	5.0	1.5	5.5	7.5	1.5	8.5	ns
t <sub>PZH</sub>	Output Enable Time	5.0	1.5	7.0	8.5	1.0	9.5	ns
t <sub>PZL</sub>	Output Enable Time	5.0	2.0	7.0	9.5	1.5	10.5	ns
t <sub>PHZ</sub>	Output Disable Time	5.0	2.0	8.0	9.5	2.0	10.5	ns
t <sub>PLZ</sub>	Output Disable Time	5.0	2.5	6.5	10.0	2.0	10.5	ns

<sup>7.</sup> Voltage range 5.0 is 5.0 V ± 0.5 V.

# **CAPACITANCE**

Symbol	Parameter	Conditions	Тур.	Units
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = OPEN	4.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance	V <sub>CC</sub> = 5.0 V	45.0	pF

#### **ORDERING INFORMATION**

Device Device Marking		Package	Shipping <sup>†</sup>
74AC240SCX	AC240	SOIC-20W, case 751BJ (Pb-Free)	1000 Units / Tape & Reel
74ACT240SCX	ACT240	SOIC-20W, case 751BJ (Pb-Free)	1000 Units / Tape & Reel
74ACT240MTC	ACT 240	TSSOP-20, case 948E (Pb-Free)	75 Units / Tube
74ACT240MTCX	ACT 240	TSSOP-20, case 948AQ (Pb-Free)	2500 Units / Tape & Reel

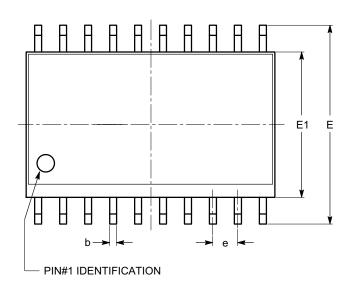
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NOTE: All packages are lead free per JEDEC: J-STD-020B standard.



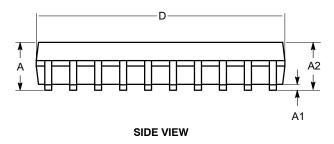
SOIC-20, 300 mils CASE 751BJ-01 ISSUE O

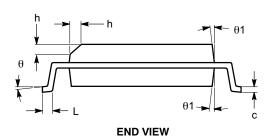
**DATE 19 DEC 2008** 



SYMBOL	MIN	NOM	MAX
А	2.36	2.49	2.64
A1	0.10		0.30
A2	2.05		2.55
b	0.31	0.41	0.51
С	0.20	0.27	0.33
D	12.60	12.80	13.00
Е	10.01	10.30	10.64
E1	7.40	7.50	7.60
е		1.27 BSC	
h	0.25		0.75
L	0.40	0.81	1.27
θ	0°		8°
θ1	5°		15°

**TOP VIEW** 





#### Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-013.

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DESCRIPTION:	SOIC-20, 300 MILS		PAGE 1 OF 1

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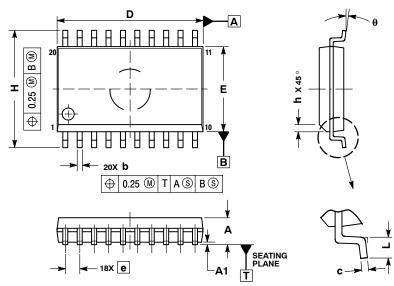




SOIC-20 WB CASE 751D-05 **ISSUE H** 

**DATE 22 APR 2015** 

# SCALE 1:1



- DIMENSIONS ARE IN MILLIMETERS.
   INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.35	2.65	
A1	0.10	0.25	
b	0.35	0.49	
С	0.23	0.32	
D	12.65	12.95	
E	7.40	7.60	
е	1.27 BSC		
Н	10.05	10.55	
h	0.25	0.75	
L	0.50	0.90	
A	0 °	7 °	

#### **RECOMMENDED SOLDERING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

# **GENERIC MARKING DIAGRAM\***



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	SOIC-20 WB		PAGE 1 OF 1

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<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

0.100 (0.004) -T- SEATING

16X

1.26

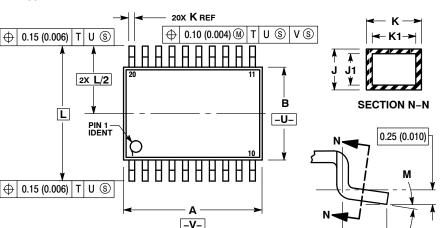
**SOLDERING FOOTPRINT** 

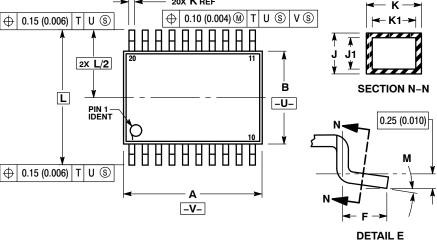
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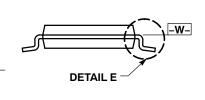


# TSSOP-20 WB CASE 948E ISSUE D

**DATE 17 FEB 2016** 







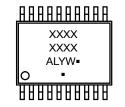
#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K
- (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

  7. DIMENSION A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	6.40	6.60	0.252	0.260	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65 BSC		0.026	26 BSC	
Н	0.27	0.37	0.011	0.015	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40 BSC		0.252	BSC	
М	٥°	80	٥°	80	

# **GENERIC MARKING DIAGRAM\***



= Assembly Location

= Wafer Lot

= Year

= Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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DESCRIPTION:	TSSOP-20 WB		PAGE 1 OF 1

DIMENSIONS: MILLIMETERS

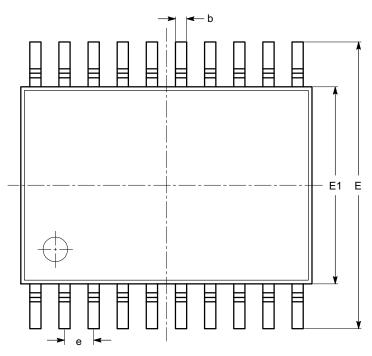
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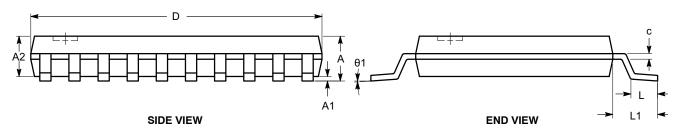
**TSSOP20, 4.4x6.5**CASE 948AQ-01
ISSUE A

**DATE 19 MAR 2009** 



SYMBOL	MIN	NOM	MAX
Α			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
С	0.09		0.20
D	6.40	6.50	6.60
Е	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°

**TOP VIEW** 



#### Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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